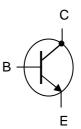


## 2N5681 - 2N5682

## **NPN SWITCHING TRANSISTORS**

The 2N5681 and 2N5682 are silicon expitaxial planar PNP transistors in jedec TO-39 metal case. They are intended for use as drivers for high power transistors in general purpose, amplifier and switching circuit. The complementary PNP types are the 2N5679 and 2N5680 . Compliance to RoHS.



### **ABSOLUTE MAXIMUM RATINGS**

Cymphal	Ratings		Val	I Incit	
Symbol			25681	2N5682	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	I <sub>B</sub> =0	100	120	V
V <sub>CBO</sub>	Collector-Base Voltage	I <sub>E</sub> =0	100	120	V
$V_{EBO}$	Emitter-Base Voltage	I <sub>C</sub> =0	4		V
Ic	Collector Current		1		Α
I <sub>B</sub>	Base Current		500		mA
P <sub>D</sub>	Total Power Dissipation	T <sub>amb</sub> = 25℃	1		W
		T <sub>case</sub> = 25℃	10		
TJ	Junction Temperature		200		<u>ر</u>
T <sub>Stg</sub>	Storage Temperature range		-65 to +150		

#### THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R <sub>thJ-a</sub>	Thermal Resistance, Junction to ambient	175	℃/W
R <sub>thJ-c</sub>	Thermal Resistance, Junction to case	17.5	€/W



# 2N5681 - 2N5682

## **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

Symbol	Ratings	Test Condition(s)		Min	Тур	Mx	Unit
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 100 \text{ V}, I_{E} = 0$	2N5679	-	-	1	μΑ
		$V_{CB} = 120 \text{ V}, I_{E} = 0$	2N5680				
I <sub>CEO</sub>	Collector Cutoff	$V_{CE} = 70 \text{ V}, I_{B} = 0$	2N5679	_	-	10	μA
	Current	$V_{CE} = 80 \text{ V}, I_{B} = 0$	2N5680				
I <sub>CEV</sub>	Collector Cutoff Current	$V_{CE} = 100 \text{ V}, V_{BE} = -1.5 \text{ V}$	2N5679	_	-	1	μΑ
		$V_{CE} = 120 \text{ V}, V_{BE} = -1.5 \text{ V}$	2N5680				
		$V_{CE} = 100 \text{ V}, V_{BE} = -1.5 \text{ V}$ $T_{C} = 150 \text{ C}$	2N5679	- -	1	1	mA
		V <sub>CE</sub> = 120 V, V <sub>BE</sub> = -1.5 V T <sub>C</sub> = 150℃	2N5680				
	Emitter Cutoff Current	$V_{BE} = 4.0 \text{ V}, I_{C} = 0$	2N5679		-	1	μA
I <sub>EBO</sub>			2N5680				
V	Collector Emitter Sustaining voltage (*)	$I_C = 10 \text{ mA}, I_B = 0$	2N5679	100	-	-	V
V <sub>CEO(sus)</sub>			2N5680	120	-	-	
	Collector-Emitter saturation Voltage (*)	$I_{\rm C} = 250 \text{ mA}$	2N5679	_	-	0.6	
V <sub>CE(SAT)</sub>		$I_B = 25 \text{ mA}$	2N5680				
		$I_{\rm C} = 500  \text{mA}$	2N5679	_	- 1 - 2	1	
V CE(SAT)		$I_B = 50 \text{ mA}$	2N5680				
		$I_C = 1 A$	2N5679	_			
		I <sub>B</sub> = 200 mA	2N5680				
V <sub>BE</sub>	Base-Emitter Voltage (*)	$I_C = 250 \text{ mA}, V_{CE} = 2 \text{ V}$	2N5679	_	-	1	V
* BE			2N5680				
	DC Current Gain (*)	$I_C = 250 \text{ mA}, V_{CE} = 2 \text{ V}$	2N5679	40	-	150	
h <sub>FE</sub>			2N5680				
		I <sub>C</sub> = 1 A, V <sub>CE</sub> = 2 V	2N5679 2N5680	5	-	-	
f <sub>T</sub>	Transition frequency	$I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$	2N5679	30	-	-	MHz
• 1		f = 10 MHz	2N5680				1711 12
Сов	Output Capacitance	$I_E = 0$ , $V_{CB} = 20 \text{ V}$ f = 1MHz	2N5679 2N5680	_	-	50	pF
	Small Signal Current Gain	$I_C = 200 \text{ mA}, V_{CE} = 1.5 \text{ V}$	2N5679	40		-	-
h <sub>fe</sub>		f = 1 kHz	2N5680		-		
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<sup>(\*)</sup> Pulse Width  $\approx$  300  $\mu$ s, Duty Cycle  $\angle$  2.0%

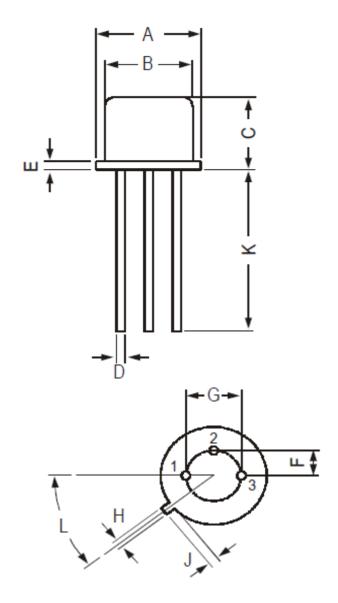


## 2N5681 - 2N5682

### **MECHANICAL DATA CASE TO-39**

DIMENSIONS (mm)				
	min	max		
Α	8.50	9.39		
В	7.74	8.50		
С	6.09	6.60		
D	0.40	0.53		
Е	-	0.88		
F	2.41	2.66		
G	4.82	5.33		
Н	0.71	0.86		
J	0.73	1.02		
K	12.70	-		
L	42°	48°		

Pin 1 :	Emitter
Pin 2 :	Base
Pin 3 :	Collector
Case :	Collector



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